

SN54LVTH543, SN74LVTH543 3.3-V ABT OCTAL REGISTERED TRANSCEIVERS WITH 3-STATE OUTPUTS

SCBS704D – AUGUST 1997 – REVISED APRIL 1999

- State-of-the-Art Advanced BiCMOS Technology (ABT) Design for 3.3-V Operation and Low Static-Power Dissipation
- I_{off} and Power-Up 3-State Support Hot Insertion
- Bus Hold on Data Inputs Eliminates the Need for External Pullup/Pulldown Resistors
- Support Mixed-Mode Signal Operation (5-V Input and Output Voltages With 3.3-V V_{CC})
- Support Unregulated Battery Operation Down to 2.7 V
- Typical V_{OLP} (Output Ground Bounce) < 0.8 V at $V_{CC} = 3.3$ V, $T_A = 25^\circ\text{C}$
- Latch-Up Performance Exceeds 500 mA Per JESD 17
- ESD Protection Exceeds 2000 V Per MIL-STD-883, Method 3015; Exceeds 200 V Using Machine Model ($C = 200$ pF, $R = 0$)
- Package Options Include Plastic Small-Outline (DW), Shrink Small-Outline (DB), Thin Shrink Small-Outline (PW), and Thin Very Small-Outline (DGV) Packages, Ceramic Chip Carriers (FK), Ceramic Flat (W) Package, and Ceramic (JT) DIPs

description

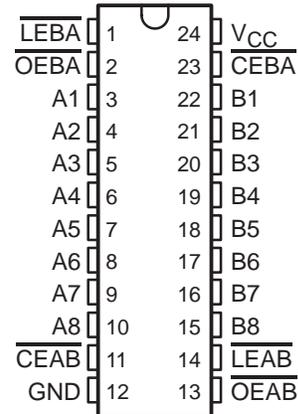
These octal transceivers are designed specifically for low-voltage (3.3-V) V_{CC} operation, but with the capability to provide a TTL interface to a 5-V system environment.

The 'LVTH543 devices contain two sets of D-type latches for temporary storage of data flowing in either direction. Separate latch-enable (\overline{LEAB} or \overline{LEBA}) and output-enable (\overline{OEAB} or \overline{OEBA}) inputs are provided for each register to permit independent control in either direction of data flow.

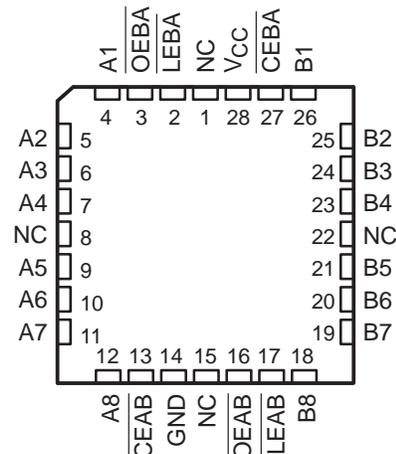
The A-to-B enable (\overline{CEAB}) input must be low to enter data from A or to output data from B. If \overline{CEAB} is low and \overline{LEAB} is low, the A-to-B latches are transparent; a subsequent low-to-high transition of \overline{LEAB} puts the A latches in the storage mode. With \overline{CEAB} and \overline{OEAB} both low, the 3-state B outputs are active and reflect the data present at the output of the A latches. Data flow from B to A is similar, but requires using the \overline{CEBA} , \overline{LEBA} , and \overline{OEBA} inputs.

Active bus-hold circuitry is provided to hold unused or floating data inputs at a valid logic level.

SN54LVTH543 . . . JT OR W PACKAGE
SN74LVTH543 . . . DB, DGV, DW, OR PW PACKAGE
(TOP VIEW)



SN54LVTH543 . . . FK PACKAGE
(TOP VIEW)



NC – No internal connection



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**TEXAS
INSTRUMENTS**

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description (continued)

When V_{CC} is between 0 and 1.5 V, the device is in the high-impedance state during power up or power down. However, to ensure the high-impedance state above 1.5 V, \overline{OE} should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

This device is fully specified for hot-insertion applications using I_{off} and power-up 3-state. The I_{off} circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down. The power-up 3-state circuitry places the outputs in the high-impedance state during power up and power down, which prevents driver conflict.

The SN54LVTH543 is characterized for operation over the full military temperature range of -55°C to 125°C . The SN74LVTH543 is characterized for operation from -40°C to 85°C .

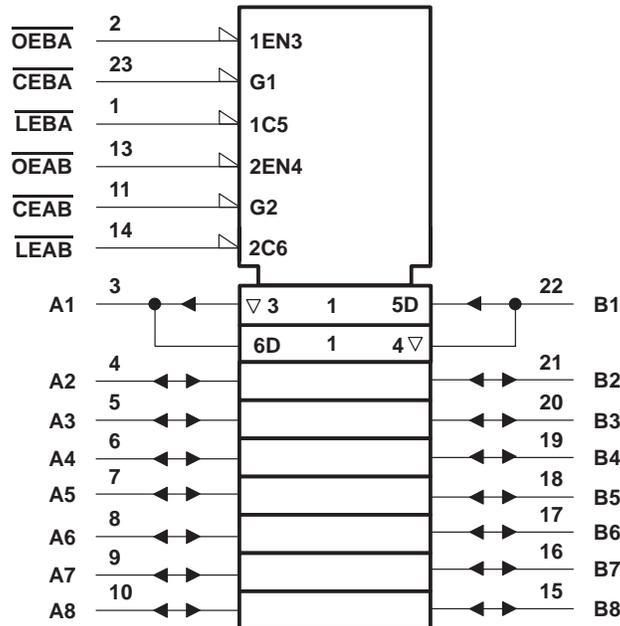
FUNCTION TABLE†

INPUTS				OUTPUT
\overline{CEAB}	\overline{LEAB}	\overline{OEAB}	A	B
H	X	X	X	Z
X	X	H	X	Z
L	H	L	X	B_0^{\ddagger}
L	L	L	L	L
L	L	L	H	H

† A-to-B data flow is shown; B-to-A flow control is the same except that it uses \overline{CEBA} , \overline{LEBA} , and \overline{OEBA} .

‡ Output level before the indicated steady-state input conditions were established

logic symbol§

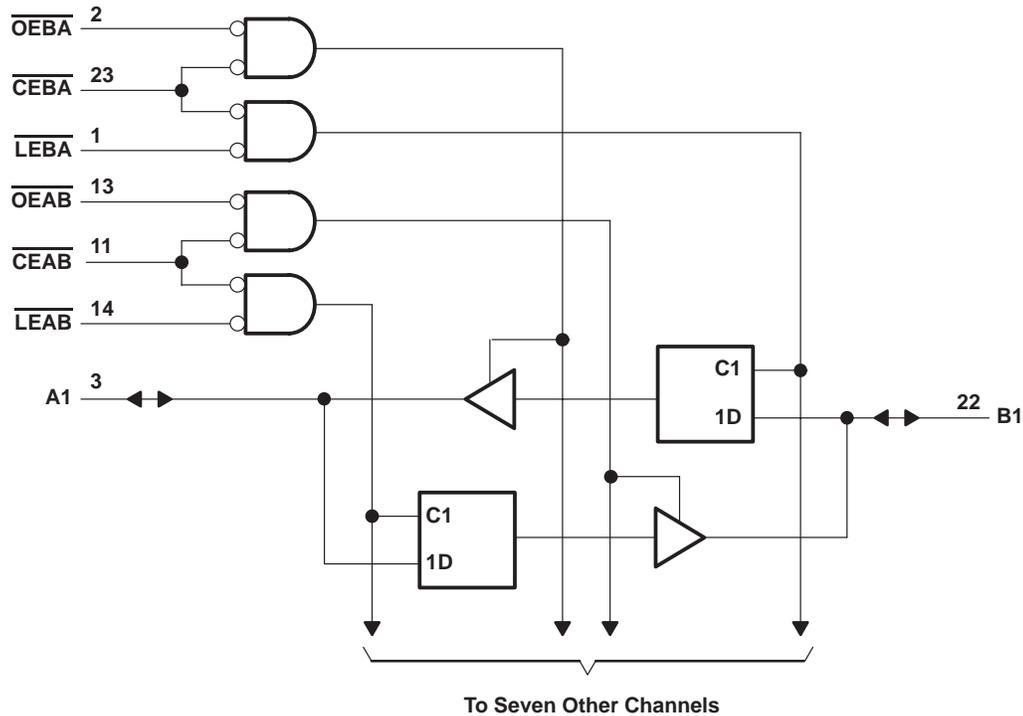


§ This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12. Pin numbers shown are for the DB, DGV, DW, JT, PW, and W packages.

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logic diagram (positive logic)



Pin numbers shown are for the DB, DGV, DW, JT, PW, and W packages.

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage range, V_{CC}	-0.5 V to 4.6 V
Input voltage range, V_I (see Note 1)	-0.5 V to 7 V
Voltage range applied to any output in the high-impedance or power-off state, V_O (see Note 1)	-0.5 V to 7 V
Voltage range applied to any output in the high state, V_O (see Note 1)	-0.5 V to $V_{CC} + 0.5$ V
Current into any output in the low state, I_O : SN54LVTH543	96 mA
SN74LVTH543	128 mA
Current into any output in the high state, I_O (see Note 2): SN54LVTH543	48 mA
SN74LVTH543	64 mA
Input clamp current, I_{IK} ($V_I < 0$)	-50 mA
Output clamp current, I_{OK} ($V_O < 0$)	-50 mA
Package thermal impedance, θ_{JA} (see Note 3): DB package	104°C/W
DGV package	139°C/W
DW package	81°C/W
PW package	120°C/W
Storage temperature range, T_{stg}	-65°C to 150°C

† Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- NOTES: 1. The input and output negative-voltage ratings may be exceeded if the input and output clamp-current ratings are observed.
2. This current flows only when the output is in the high state and $V_O > V_{CC}$.
3. The package thermal impedance is calculated in accordance with JESD 51.



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recommended operating conditions (see Note 4)

		SN54LVTH543		SN74LVTH543		UNIT
		MIN	MAX	MIN	MAX	
V _{CC}	Supply voltage	2.7	3.6	2.7	3.6	V
V _{IH}	High-level input voltage	2		2		V
V _{IL}	Low-level input voltage		0.8		0.8	V
V _I	Input voltage		5.5		5.5	V
I _{OH}	High-level output current		-24		-32	mA
I _{OL}	Low-level output current		48		64	mA
Δt/Δv	Input transition rise or fall rate	Outputs enabled		10	10	ns/V
Δt/ΔV _{CC}	Power-up ramp rate	200		200		μs/V
T _A	Operating free-air temperature	-55	125	-40	85	°C

NOTE 4: All unused control inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.

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electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS		SN54LVTH543		SN74LVTH543		UNIT		
				MIN	TYP†	MAX	MIN		TYP†	MAX
V_{IK}		$V_{CC} = 2.7\text{ V}$, $I_I = -18\text{ mA}$		-1.2		-1.2		V		
V_{OH}		$V_{CC} = 2.7\text{ V to }3.6\text{ V}$, $I_{OH} = -100\text{ }\mu\text{A}$		$V_{CC}-0.2$		$V_{CC}-0.2$		V		
		$V_{CC} = 2.7\text{ V}$, $I_{OH} = -8\text{ mA}$		2.4		2.4				
		$V_{CC} = 3\text{ V}$		$I_{OH} = -24\text{ mA}$		2			$I_{OH} = -32\text{ mA}$	
V_{OL}		$V_{CC} = 2.7\text{ V}$		$I_{OL} = 100\text{ }\mu\text{A}$		0.2		0.2		
				$I_{OL} = 24\text{ mA}$		0.5		0.5		
		$V_{CC} = 3\text{ V}$		$I_{OL} = 16\text{ mA}$		0.4		0.4		
				$I_{OL} = 32\text{ mA}$		0.5		0.5		
				$I_{OL} = 48\text{ mA}$		0.55		0.55		
				$I_{OL} = 64\text{ mA}$				0.55		
I_I		Control inputs $V_{CC} = 3.6\text{ V}$, $V_I = V_{CC}$ or GND $V_{CC} = 0$ or 3.6 V , $V_I = 5.5\text{ V}$		± 1		± 1		μA		
				10		10				
		A or B ports‡ $V_{CC} = 3.6\text{ V}$		$V_I = 5.5\text{ V}$		20			20	
				$V_I = V_{CC}$		1			1	
		$V_I = 0$		-5		-5				
I_{off}		$V_{CC} = 0$, V_I or $V_O = 0$ to 4.5 V				± 100		μA		
$I_I(\text{hold})$		$V_{CC} = 3\text{ V}$		$V_I = 0.8\text{ V}$		75		75		
				$V_I = 2\text{ V}$		-75		-75		
		$V_{CC} = 3.6\text{ V}\S$		$V_I = 0$ to 3.6 V				± 500		
I_{OZPU}		$V_{CC} = 0$ to 1.5 V , $V_O = 0.5$ to 3 V , $OE = \text{don't care}$		$\pm 100^*$		± 100		μA		
I_{OZPD}		$V_{CC} = 1.5\text{ V}$ to 0 , $V_O = 0.5$ to 3 V , $OE = \text{don't care}$		$\pm 100^*$		± 100		μA		
I_{CC}		$V_{CC} = 3.6\text{ V}$, $I_O = 0$, $V_I = V_{CC}$ or GND		Outputs high		0.19		0.19		
				Outputs low		5		5		
				Outputs disabled		0.19		0.19		
$\Delta I_{CC}\P$		$V_{CC} = 3\text{ V to }3.6\text{ V}$, One input at $V_{CC} - 0.6\text{ V}$, Other inputs at V_{CC} or GND		0.2		0.2		mA		
C_i		$V_I = 3\text{ V}$ or 0		4		4		pF		
C_{io}		$V_O = 3\text{ V}$ or 0		9		9		pF		

* On products compliant to MIL-PRF-38535, this parameter is not production tested.

† All typical values are at $V_{CC} = 3.3\text{ V}$, $T_A = 25^\circ\text{C}$.

‡ Unused terminals are at V_{CC} or GND.

§ This is the bus-hold maximum dynamic current. It is the minimum overdrive current required to switch the input from one state to another.

P This is the increase in supply current for each input that is at the specified TTL voltage level rather than V_{CC} or GND.

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timing requirements over recommended operating free-air temperature range (unless otherwise noted) (see Figure 1)

			SN54LVTH543				SN74LVTH543				UNIT
			$V_{CC} = 3.3\text{ V} \pm 0.3\text{ V}$		$V_{CC} = 2.7\text{ V}$		$V_{CC} = 3.3\text{ V} \pm 0.3\text{ V}$		$V_{CC} = 2.7\text{ V}$		
			MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
t_w	Pulse duration, $\overline{\text{LEAB}}$ or $\overline{\text{LEBA}}$ low		3.3		3.3		3.3		3.3	ns	
t_{su}	Setup time	A or B before $\overline{\text{LEAB}}$ or $\overline{\text{LEBA}}\uparrow$	Data high	0.4		0.4		0.4		0.4	ns
			Data low	1		1.5		1		1.5	
		A or B before $\overline{\text{CEAB}}$ or $\overline{\text{CEBA}}\uparrow$	Data high	0.2		0.2		0.2		0.2	
			Data low	0.7		1.2		0.7		1.2	
t_h	Hold time	A or B after $\overline{\text{LEAB}}$ or $\overline{\text{LEBA}}\uparrow$	Data high	1.5		0.6		1.5		0.6	ns
			Data low	1.3		1.5		1.3		1.5	
		A or B after $\overline{\text{CEAB}}$ or $\overline{\text{CEBA}}\uparrow$	Data high	1.6		0.5		1.6		0.5	
			Data low	1.4		1.6		1.4		1.6	

switching characteristics over recommended operating free-air temperature range, $C_L = 50\text{ pF}$ (unless otherwise noted) (see Figure 1)

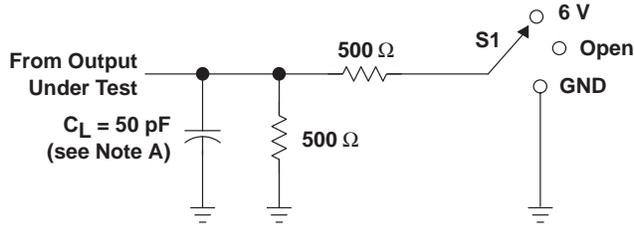
PARAMETER	FROM (INPUT)	TO (OUTPUT)	SN54LVTH543				SN74LVTH543				UNIT	
			$V_{CC} = 3.3\text{ V} \pm 0.3\text{ V}$		$V_{CC} = 2.7\text{ V}$		$V_{CC} = 3.3\text{ V} \pm 0.3\text{ V}$			$V_{CC} = 2.7\text{ V}$		
			MIN	MAX	MIN	MAX	MIN	TYP†	MAX	MIN		MAX
t_{PLH}	A or B	B or A	1.2	3.9		4.5	1.3	2.5	3.7		4.3	ns
t_{PHL}			1.2	3.9		4.5	1.3	2.5	3.7		4.3	
t_{PLH}	$\overline{\text{LE}}$	A or B	1.2	5.1		6.1	1.3	2.9	4.7		5.9	ns
t_{PHL}			1.2	5.1		6.1	1.3	2.9	4.7		5.9	
t_{PZH}	$\overline{\text{OE}}$	A or B	1	5.1		6.4	1.1	2.9	4.9		6.2	ns
t_{PZL}			1	5.1		6.4	1.1	3.2	4.9		6.2	
t_{PHZ}	$\overline{\text{OE}}$	A or B	1.9	5.6		6.2	2	3.4	5.3		5.9	ns
t_{PLZ}			1.9	5.6		6.2	2	3.7	5.3		5.9	
t_{PZH}	$\overline{\text{CE}}$	A or B	1.2	5.5		7	1.3	3.2	5.3		6.8	ns
t_{PZL}			1.2	5.5		7	1.3	3.5	5.3		6.8	
t_{PHZ}	$\overline{\text{CE}}$	A or B	2.2	5.7		6.2	2.3	3.8	5.4		5.9	ns
t_{PLZ}			2.2	5.7		5.9	2.3	3.9	5.4		5.6	

† All typical values are at $V_{CC} = 3.3\text{ V}$, $T_A = 25^\circ\text{C}$.

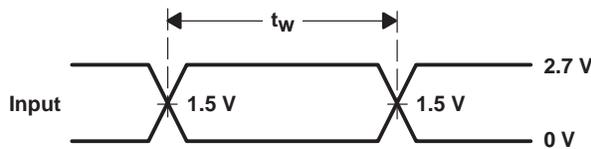
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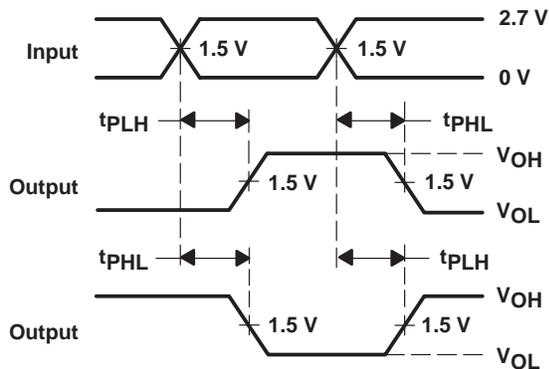
PARAMETER MEASUREMENT INFORMATION



LOAD CIRCUIT

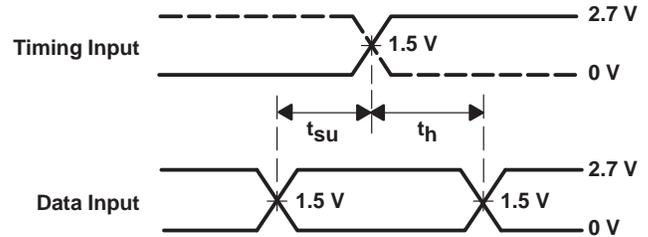


VOLTAGE WAVEFORMS
PULSE DURATION

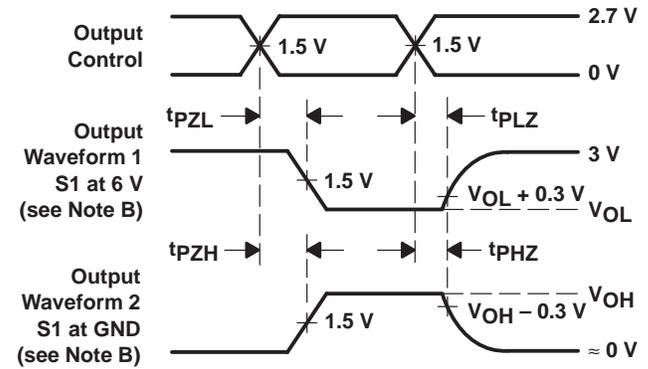


VOLTAGE WAVEFORMS
PROPAGATION DELAY TIMES
INVERTING AND NONINVERTING OUTPUTS

TEST	S1
t_{PLH}/t_{PHL}	Open
t_{PLZ}/t_{PZL}	6 V
t_{PHZ}/t_{PZH}	GND



VOLTAGE WAVEFORMS
SETUP AND HOLD TIMES



VOLTAGE WAVEFORMS
ENABLE AND DISABLE TIMES
LOW- AND HIGH-LEVEL ENABLING

- NOTES:
- C_L includes probe and jig capacitance.
 - Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
 - All input pulses are supplied by generators having the following characteristics: $PRR \leq 10 \text{ MHz}$, $Z_O = 50 \Omega$, $t_r \leq 2.5 \text{ ns}$, $t_f \leq 2.5 \text{ ns}$.
 - The outputs are measured one at a time with one transition per measurement.

Figure 1. Load Circuit and Voltage Waveforms

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